

## Electronic Supplementary Information (ESI) to:

### Tuning the surface electronic structure of a $\text{Pt}_3\text{Ti}(111)$ electro catalyst

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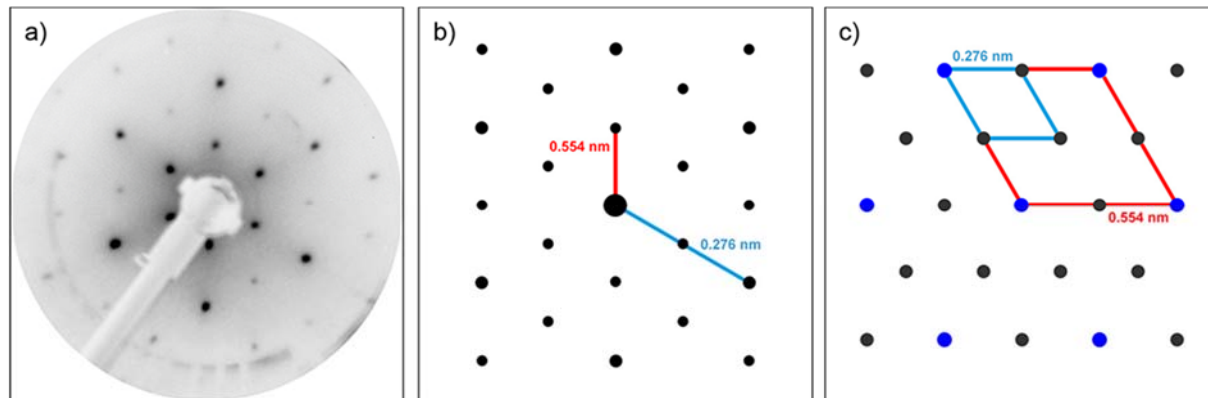
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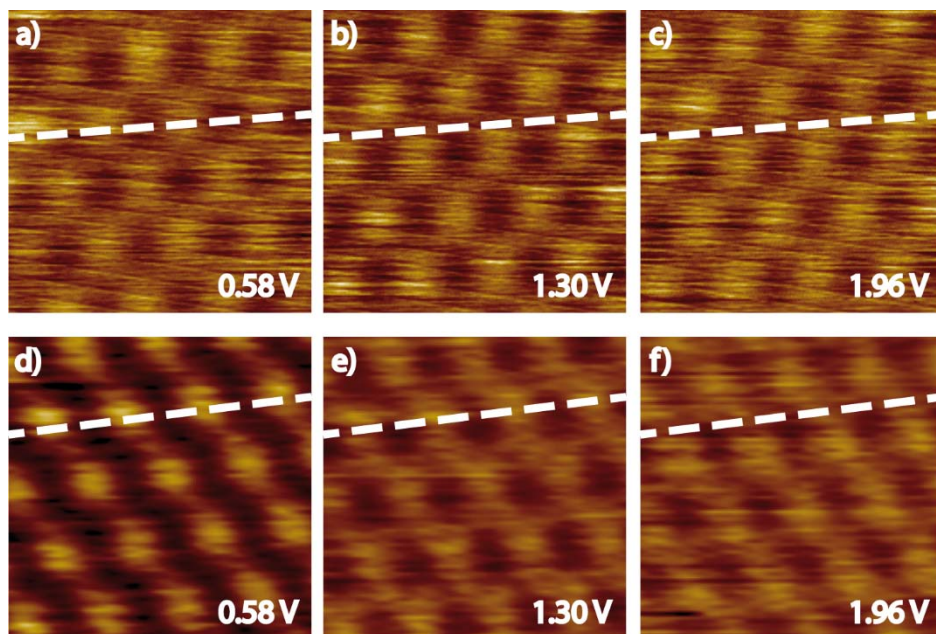
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#### LEED measurements



**Fig. S1** (a) LEED image (180 eV) of the  $\text{Pt}_3\text{Ti}(111)$  surface showing a Ti induced  $p(2 \times 2)$  superstructure on the hexagonal substrate. The  $p(1 \times 1)$  structure is related to the Pt sublattice. (b)  $k$ -space model of the LEED image with the lattice vectors of the superstructure and the sublattice. (c) real space model of the LEED image with both unit cells.

## STM measurements



**Fig. S2** STM measurements of the surface of S1 (a)-(c) and S2 (d)-(f) obtained in the multiple voltage mode. For S1 the change in the appearing shift takes place between 0.58 V and 1.30 V, while for S2 the shift takes place between 1.30 V and 1.96 V (set-point values: (a) 0.58 V, 7.9 nA; (b) 1.30 V, 7.9 nA; (c) 1.96 V, 7.9 nA; (d) 0.58 V, 0.6 nA; (e) 1.30 V, 0.6 nA; (f) 1.96 V, 0.6 nA).

## Sputtering Yield

	He <sup>+</sup>	Ne <sup>+</sup>	Ar <sup>+</sup>	Kr <sup>+</sup>	Xe <sup>+</sup>
Pt	0.035	0.70	1.56	2.11	2.23
Ti	0.08	0.45	0.58	0.53	0.50

**Tab. S1** Sputtering Yield (atoms/incident ion) of the single metal components for different noble gas ions at 0.6 keV.<sup>1,2</sup>

## References

- 1 D. Rosenberg, G. K. Wehner, *J. Appl. Phys.*, 1962, **33**, 1842-1845.
- 2 N. Laegreid, G. K. Wehner, *J. Appl. Phys.*, 1961, **32**, 365-369.